

**isc Silicon NPN Darlington Power Transistor**

**BDT65/A/B/C**

**DESCRIPTION**

- Collector Current  $I_C = 12A$
- High DC Current Gain  $h_{FE} = 1000(\text{Min}) @ I_C = 5A$
- Complement to Type BDT64/A/B/C

**APPLICATIONS**

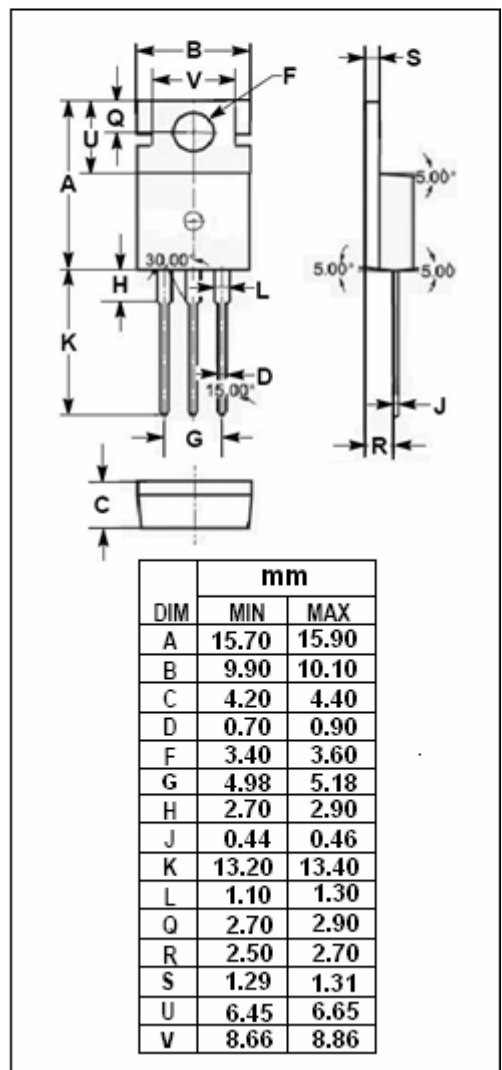
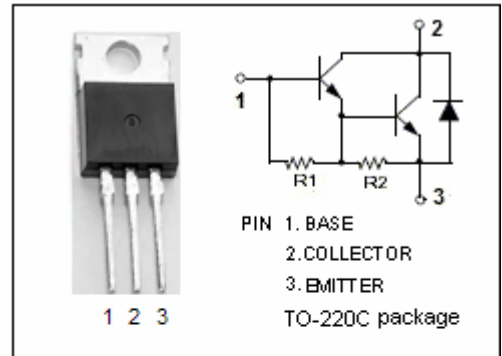
- Designed for audio output stages and general purpose amplifier applications

**ABSOLUTE MAXIMUM RATINGS( $T_a = 25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{CER}$	Collector-Emitter Voltage	BDT65	60	V
		BDT65A	80	
		BDT65B	100	
		BDT65C	120	
$V_{CEO}$	Collector-Emitter Voltage	BDT65	60	V
		BDT65A	80	
		BDT65B	100	
		BDT65C	120	
$V_{EBO}$	Emitter-Base Voltage	5	V	
$I_C$	Collector Current-Continuous	12	A	
$I_{CM}$	Collector Current-Peak	20	A	
$I_B$	Base Current-Continuous	0.5	A	
$P_C$	Collector Power Dissipation @ $T_C = 25^\circ C$	125	W	
$T_J$	Junction Temperature	150	$^\circ C$	
$T_{stg}$	Storage Temperature Range	-65~150	$^\circ C$	

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	1	$^\circ C/W$



## isc Silicon NPN Darlington Power Transistor

## BDT65/A/B/C

## ELECTRICAL CHARACTERISTICS

 $T_C=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C=30\text{mA}; I_B=0$	BDT65	60			V
			BDT65A	80			
			BDT65B	100			
			BDT65C	120			
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	$I_C=5\text{A}; I_B=20\text{mA}$			2.0	V	
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	$I_C=10\text{A}; I_B=100\text{mA}$			3.0	V	
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C=5\text{A}; V_{CE}=4\text{V}$			2.5	V	
$V_{ECF-1}$	C-E Diode Forward Voltage	$I_F=5\text{A}$			2.0	V	
$V_{ECF-2}$	C-E Diode Forward Voltage	$I_F=12\text{A}$		2.0		V	
$I_{CEO}$	Collector Cutoff Current	$V_{CE}=\frac{1}{2}V_{CE0max}; I_B=0$			0.2	mA	
$I_{CBO}$	Collector Cutoff Current	$V_{CB}=V_{CB0max}; I_E=0$ $V_{CB}=\frac{1}{2}V_{CB0max}; I_E=0; T_C=150^\circ\text{C}$			0.4 2.0	mA	
$I_{EBO}$	Emitter Cutoff Current	$V_{EB}=5\text{V}; I_C=0$			5	mA	
$h_{FE-1}$	DC Current Gain	$I_C=1\text{A}; V_{CE}=4\text{V}$		1500			
$h_{FE-2}$	DC Current Gain	$I_C=5\text{A}; V_{CE}=4\text{V}$	1000				
$h_{FE-3}$	DC Current Gain	$I_C=12\text{A}; V_{CE}=4\text{V}$		1000			
$C_{OB}$	Output Capacitance	$I_E=0; V_{CB}=10\text{V}; f_{test}=1\text{MHz}$		200		pF	

## Switching times

$t_{on}$	Turn-On Time	$I_C=5\text{A}; I_{B1}=-I_{B2}=20\text{mA}; V_{CC}=30\text{V}$		1	2.5	$\mu\text{s}$
$t_{off}$	Turn-Off Time			6.0	10	$\mu\text{s}$